Old Company Name in Catalogs and Other Documents

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April 1st, 2010 Renesas Electronics Corporation

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DATA SHEET



NPN SILICON GERMANIUM RF TRANSISTOR

NESG3031M05

NPN SiGE RF TRANSISTOR FOR LOW NOISE, HIGH-GAIN AMPLIFICATION FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M05, 2012 PKG)

FEATURES

- The device is an ideal choice for low noise, high-gain amplification
 - NF = 0.6 dB TYP., G_a = 16.0 dB TYP. @ V_{CE} = 2 V, I_C = 6 mA, f = 2.4 GHz

NF = 0.95 dB TYP., G_a = 10.0 dB TYP. @ V_{CE} = 2 V, I_C = 6 mA, f = 5.2 GHz

NF = 1.1 dB TYP., $G_a = 9.5$ dB TYP. @ $V_{CE} = 2$ V, $I_C = 6$ mA, f = 5.8 GHz

- Maximum stable power gain: MSG = 14.0 dB TYP. @ VcE = 3 V, Ic = 20 mA, f = 5.8 GHz
- SiGe HBT technology (UHS3) adopted: fmax = 110 GHz
- Flat-lead 4-pin thin-type super minimold (M05, 2012 PKG)

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG3031M05	NESG3031M05-A	Flat-lead 4-pin thin-type super minimold (M05, 2012 PKG)	50 pcs (Non reel)	• 8 mm wide embossed taping • Pin 3 (Collector), Pin 4 (Emitter) face the
NESG3031M05-T1	NESG3031M05-T1-A	(Pb-Free)	3 kpcs/reel	perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office. Unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vcво	12.0	V
Collector to Emitter Voltage	Vceo	4.3	V
Emitter to Base Voltage	VEBO	1.5	V
Collector Current	lc	35	mA
Total Power Dissipation	Ptot Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Note Mounted on 1.08 cm² × 1.0 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	-	_	100	nA
Emitter Cut-off Current	ІЕВО	V _{EB} = 1 V, I _C = 0 mA	ı	ı	100	nA
DC Current Gain	hfE Note 1	VcE = 2 V, Ic = 6 mA	220	300	380	1
RF Characteristics						
Insertion Power Gain	S _{21e} ²	VcE = 3 V, Ic = 20 mA, f = 5.8 GHz	6.0	8.5	1	dB
Noise Figure (1)	NF	$\begin{aligned} &V_{\text{CE}} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 2.4 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, }} Z_{\text{L}} = Z_{\text{Lopt}} \end{aligned}$	_	0.6	_	dB
Noise Figure (2)	NF	$\begin{aligned} &V_{\text{CE}} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.2 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{aligned}$	-	0.95	-	dB
Noise Figure (3)	NF	$V_{CE} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.8 \text{ GHz,}$ $Z_S = Z_{Sopt}, Z_L = Z_{Lopt}$	_	1.1	1.5	dB
Associated Gain (1)	Ga	$V_{CE} = 2 \text{ V}, \text{ Ic} = 6 \text{ mA}, \text{ f} = 2.4 \text{ GHz}, $ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	_	16.0	_	dB
Associated Gain (2)	Ga	$\begin{aligned} &V_{\text{CE}} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.2 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = Z_{\text{Lopt}} \end{aligned}$	-	10.0	-	dB
Associated Gain (3)	Ga	$\begin{aligned} &V_{\text{CE}} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.8 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{aligned}$	7.5	9.5	-	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 2 V, IE = 0 mA, f = 1 MHz	-	0.15	0.25	pF
Maximum Stable Power Gain	MSG ^{Note 3}	VcE = 3 V, Ic = 20 mA, f = 5.8 GHz	11.0	14.0	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\begin{split} &V_{\text{CE}} = 3 \text{ V, Ic (set)} = 20 \text{ mA,} \\ &f = 5.8 \text{ GHz, Zs} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{split}$	-	13.0	I	dBm
Output 3rd Order Intercept Point	OIP ₃	$\begin{split} \text{V}_{\text{CE}} = 3 \text{ V, Ic (set)} &= 20 \text{ mA,} \\ \text{f} = 5.8 \text{ GHz, Zs} &= Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{split}$	_	18.0	_	dBm

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

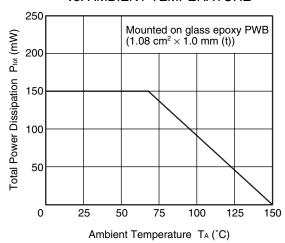
3. MSG =
$$\frac{S_{21}}{S_{12}}$$

hfe CLASSIFICATION

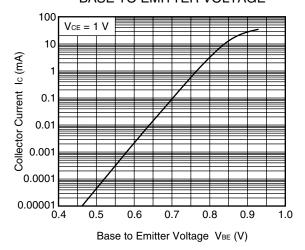
Rank	FB		
Marking	T1K		
h _{FE} Value	220 to 380		

TYPICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise specified)

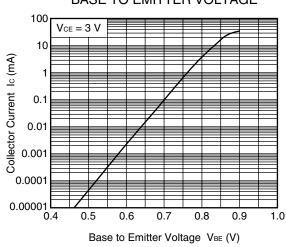
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

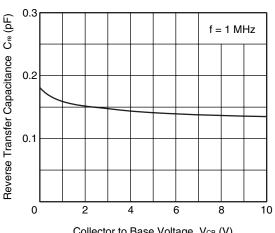


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



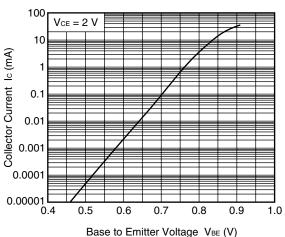
Remark The graphs indicate nominal characteristics.

REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

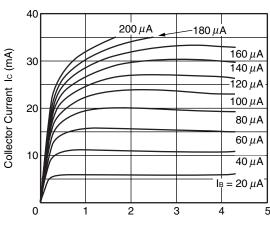


Collector to Base Voltage VcB (V)

COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

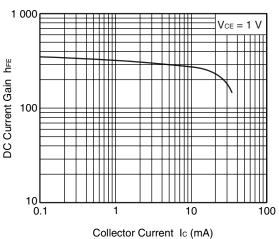


COLLECTOR CURRENT vs. **COLLECTOR TO EMITTER VOLTAGE**

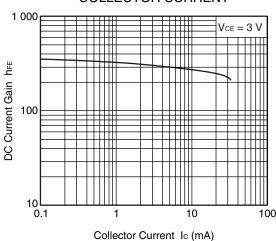


Collector to Emitter Voltage VcE (V)

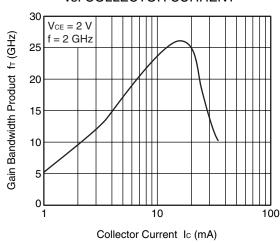
DC CURRENT GAIN vs. COLLECTOR CURRENT



DC CURRENT GAIN vs. COLLECTOR CURRENT

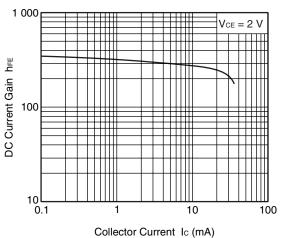


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

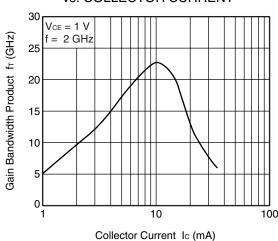


Remark The graphs indicate nominal characteristics.

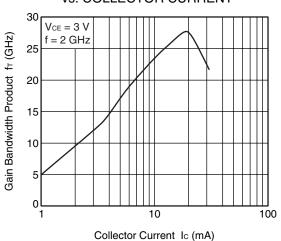
DC CURRENT GAIN vs. COLLECTOR CURRENT



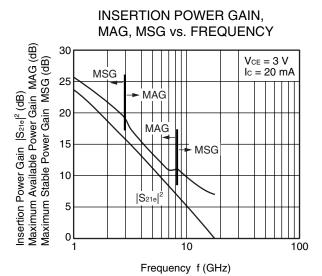
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

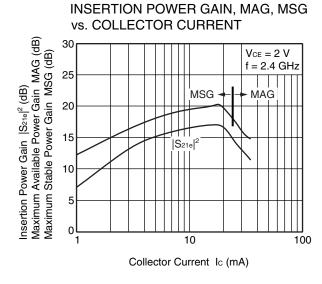


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

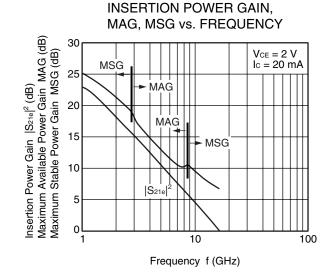


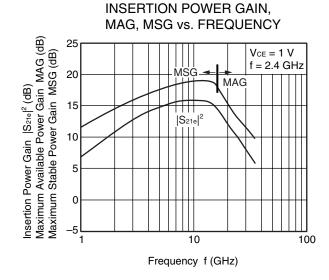
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY Maximum Available Dower Gain MAG (dB) Waximum Staple Dower Gain MSG (dB) Maximum Staple Dower Gain MSG (dB) MSG (dB) MSG (dB) MSG (dB) MAG (dB) Frequency f (GHz)

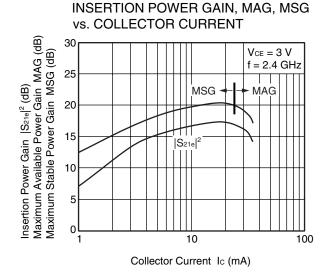




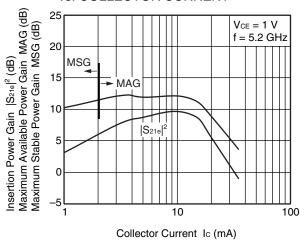
Remark The graphs indicate nominal characteristics.



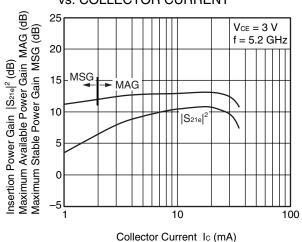




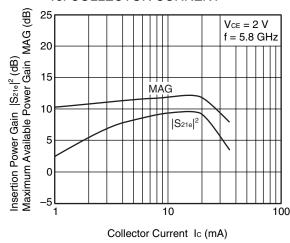
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

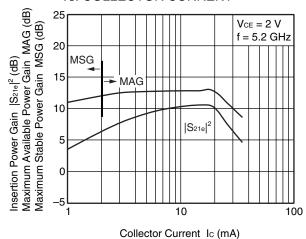


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

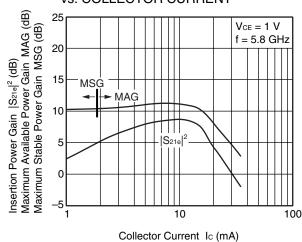


Remark The graphs indicate nominal characteristics.

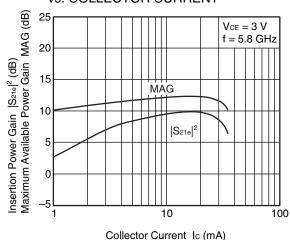
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



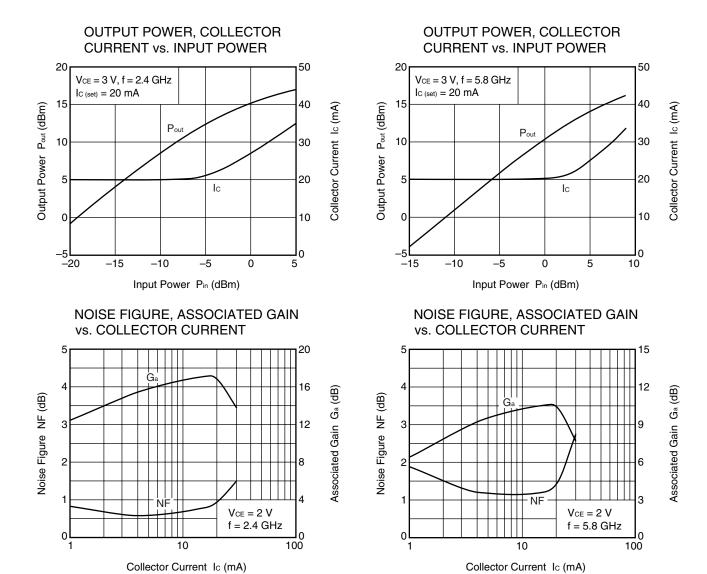
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT







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NEC NESG3031M05

<R> S-PARAMETERS

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Click here to download S-parameters.

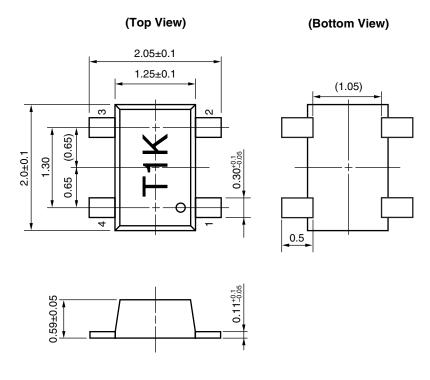
 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$

URL http://www.necel.com/microwave/en/

8

<R> PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M05, 2012 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Base
- 2. Emitter
- 3. Collector
- 4. Emitter

Remark () : Reference value

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